

**FEATURES:**

- N channel FET switches with no parasitic diode to Vcc
  - *Isolation under power-off conditions*
  - *No DC path to Vcc or GND*
  - *5V tolerant in OFF and ON state*
- 5V tolerant I/Os
- Low RON - 4Ω typical
- Flat RON characteristics over operating range
- Rail-to-rail switching 0 - 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent RON matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth - up to 500 MHz
- LVTTL-compatible control Inputs
- Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- Available in TSSOP package

**DESCRIPTION:**

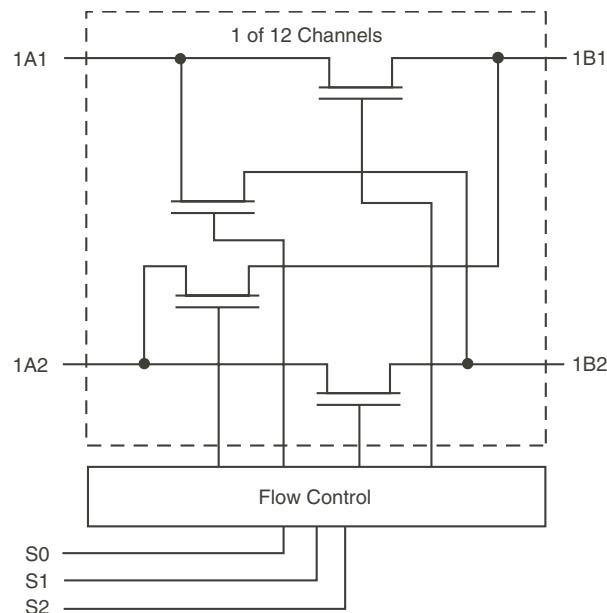
The QS3VH16212 Bus Exchange HotSwitch with 24-bits is a high bandwidth bus switch. The QS3VH16212 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The device operates as a 24-bit bus switch or a 12-bit bus exchanger, which provides data exchanging between the four signal ports through the data-select (S0 - S2) terminals. In the OFF and ON states, the switches are 5V-tolerant. In the OFF state, the switches offer very high impedance at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS3VH16212 ideal for high performance communications applications.

The QS3VH16212 is characterized for operation from -40°C to +85°C.

**APPLICATIONS:**

- Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- Low distortion analog switch
- Replaces mechanical relay
- ATM 25/155 switching

**FUNCTIONAL BLOCK DIAGRAM**

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**INDUSTRIAL TEMPERATURE RANGE**

**JANUARY 2013**

**PIN CONFIGURATION**

S0	1	56	S1
1A1	2	55	S2
1A2	3	54	1B1
2A1	4	53	1B2
2A2	5	52	2B1
3A1	6	51	2B2
3A2	7	50	3B1
GND	8	49	GND
4A1	9	48	3B2
4A2	10	47	4B1
5A1	11	46	4B2
5A2	12	45	5B1
6A1	13	44	5B2
6A2	14	43	6B1
7A1	15	42	6B2
7A2	16	41	7B1
VCC	17	40	7B2
8A1	18	39	8B1
GND	19	38	GND
8A2	20	37	8B2
9A1	21	36	9B1
9A2	22	35	9B2
10A1	23	34	10B1
10A2	24	33	10B2
11A1	25	32	11B1
11A2	26	31	11B2
12A1	27	30	12B1
12A2	28	29	12B2

TSSOP  
TOP VIEW**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

Symbol	Description	Max.	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to 4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to 5.5	V
VTERM <sup>(3)</sup>	DC Input Voltage Vin	-0.5 to 5.5	V
VAC	AC Input Voltage (pulse width $\leq$ 20ns)	-3	V
Iout	DC Output Current (max. current/pin)	120	mA
TSTG	Storage Temperature	-65 to +150	°C

**NOTES:**

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc terminals.
3. All terminals except Vcc.

**CAPACITANCE** ( $T_A = +25^\circ\text{C}$ ,  $f = 1\text{MHz}$ ,  $V_{IN} = 0\text{V}$ ,  $V_{OUT} = 0\text{V}$ )

Symbol	Parameter <sup>(1)</sup>	Typ.	Max.	Unit
C <sub>IN</sub>	Control Inputs	3	5	pF
C <sub>I/O</sub>	Quickswitch Channels (Switch OFF)	6	8	pF
C <sub>I/O</sub>	Quickswitch Channels (Switch ON)	12	16	pF

**NOTE:**

1. This parameter is guaranteed but not production tested.

**PIN DESCRIPTION**

Pin Names	I/O	Description
1Ax - 12Ax	I/O	Bus A
1Bx - 12Bx	I/O	Bus B
S <sub>0</sub> - S <sub>2</sub>	I	Data Select

**FUNCTION TABLE<sup>(1)</sup>**

S <sub>2</sub>	S <sub>1</sub>	S <sub>0</sub>	xA <sub>1</sub>	xA <sub>2</sub>	Function
L	L	L	Z	Z	Disconnect
L	L	H	xB <sub>1</sub>	Z	xA <sub>1</sub> to xB <sub>1</sub>
L	H	L	xB <sub>2</sub>	Z	xA <sub>1</sub> to xB <sub>2</sub>
L	H	H	Z	xB <sub>1</sub>	xA <sub>2</sub> to xB <sub>1</sub>
H	L	L	Z	xB <sub>2</sub>	xA <sub>2</sub> to xB <sub>2</sub>
H	L	H	Z	Z	Disconnect
H	H	L	xB <sub>1</sub>	xB <sub>2</sub>	xA <sub>1</sub> to xB <sub>1</sub> , xA <sub>2</sub> to xB <sub>2</sub>
H	H	H	xB <sub>2</sub>	xB <sub>1</sub>	xA <sub>1</sub> to xB <sub>2</sub> , xA <sub>2</sub> to xB <sub>1</sub>

**NOTE:**

1. H = HIGH Voltage Level
- L = LOW Voltage Level
- Z = High-Impedance

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE<sup>(1)</sup>

Following Conditions Apply Unless Otherwise Specified:

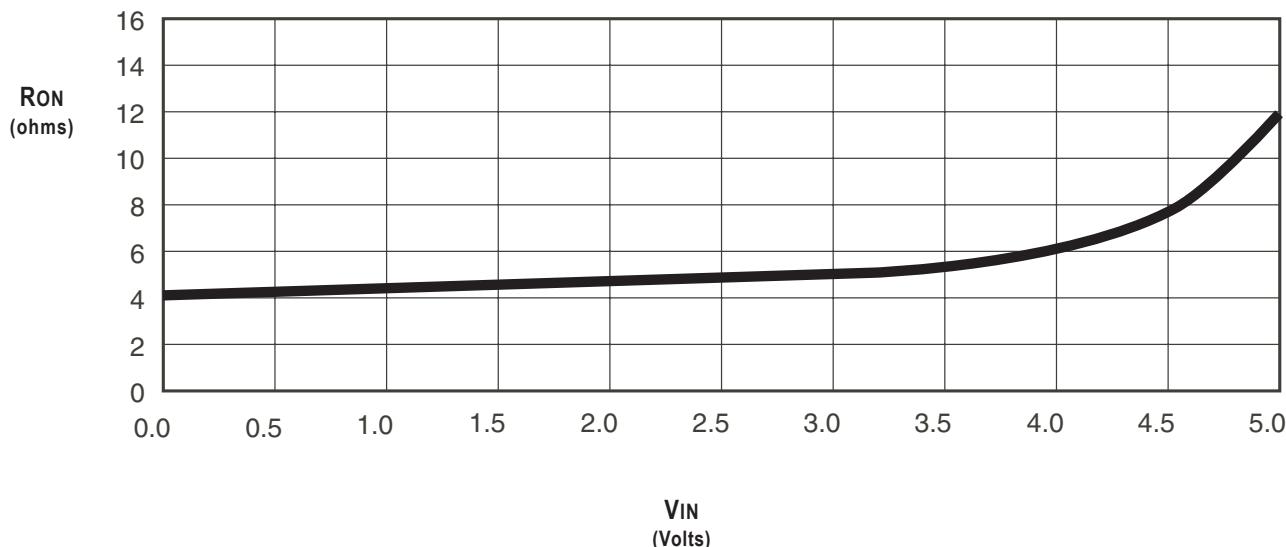
Industrial: TA = -40°C to +85°C, VCC = 3.3V ± 0.3V

Symbol	Parameter	Test Conditions			Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	VCC = 2.3V to 2.7V	1.7	—	—	—	V
			VCC = 2.7V to 3.6V	2	—	—	—	
VIL	Input LOW Voltage	Guaranteed Logic HIGH for Control Inputs	VCC = 2.3V to 2.7V	—	—	0.7	—	V
			VCC = 2.7V to 3.6V	—	—	0.8	—	
IIN	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ VCC	—	—	—	±1	μA	
IOZ	Off-State Current (Hi-Z)	0V ≤ VOUT ≤ 5V, Switches OFF	—	—	—	±1	μA	
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, VCC = 0V	—	—	—	±1	μA	
RON	Switch ON Resistance	VCC = 2.3V (Typ. at VCC = 2.5V)	VIN = 0V	ION = 30mA	—	6	8	Ω
		VIN = 1.7V	ION = 15mA	—	7	9		
		VIN = 0V	ION = 30mA	—	4	6		
		VIN = 2.4V	ION = 15mA	—	5	8		

NOTE:

1. Typical values are at VCC = 3.3V and TA = 25°C, unless otherwise noted.

## TYPICAL ON RESISTANCE vs VIN AT VCC = 3.3V



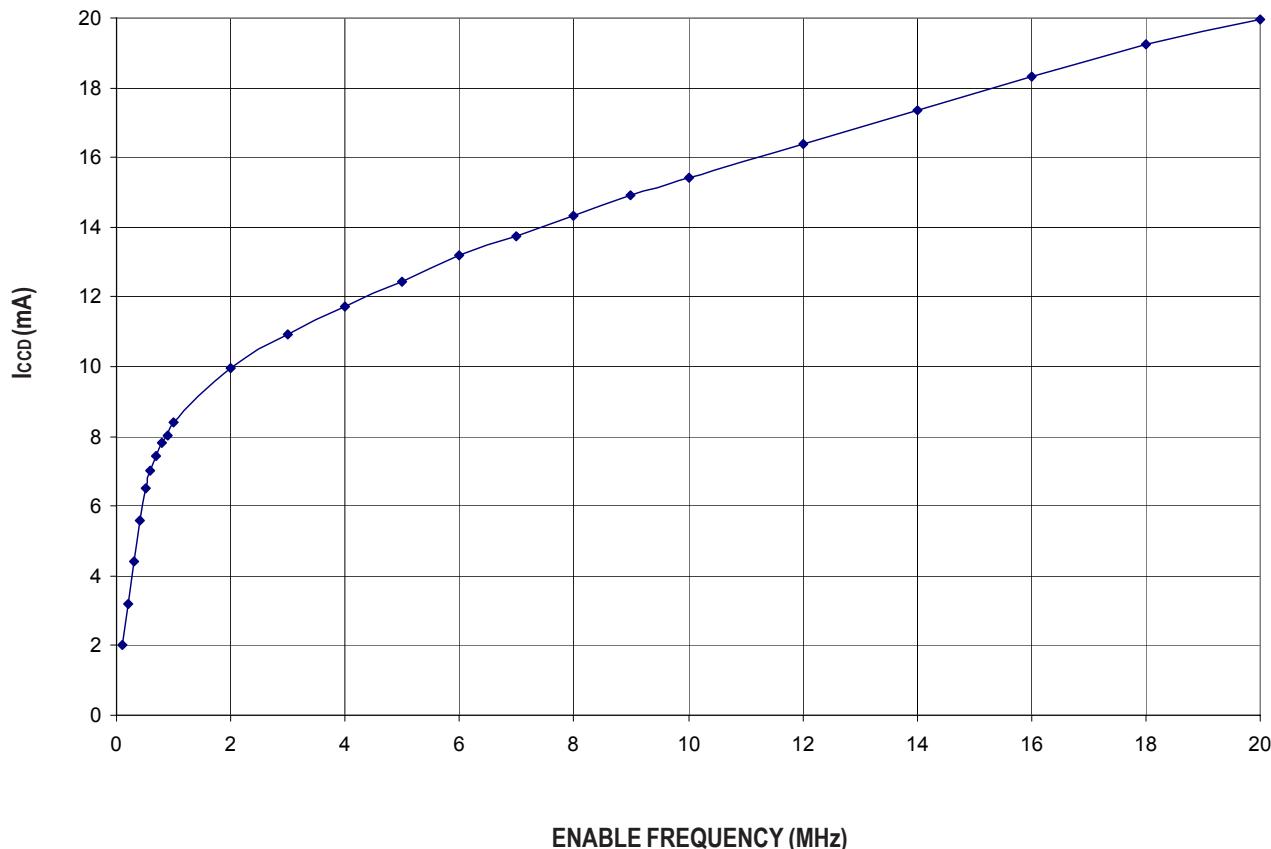
## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
I <sub>CCQ</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max., V <sub>IN</sub> = GND or V <sub>CC</sub> , f = 0	—	1.5	3	mA
ΔI <sub>CC</sub>	Power Supply Current <sup>(2,3)</sup> per Input HIGH	V <sub>CC</sub> = Max., V <sub>IN</sub> = 3V, f = 0 per Control Input	—	—	30	μA
I <sub>CCD</sub>	Dynamic Power Supply Current <sup>(4)</sup>	V <sub>CC</sub> = 3.3V, A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	See Typical I <sub>CCD</sub> vs Enable Frequency graph below			

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per input driven at the specified level. A and B pins do not contribute to ΔI<sub>CC</sub>.
3. This parameter is guaranteed but not tested.
4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

## TYPICAL I<sub>CCD</sub> VS ENABLE FREQUENCY CURVE AT V<sub>CC</sub> = 3.3V



**SWITCHING CHARACTERISTICS OVER OPERATING RANGE**

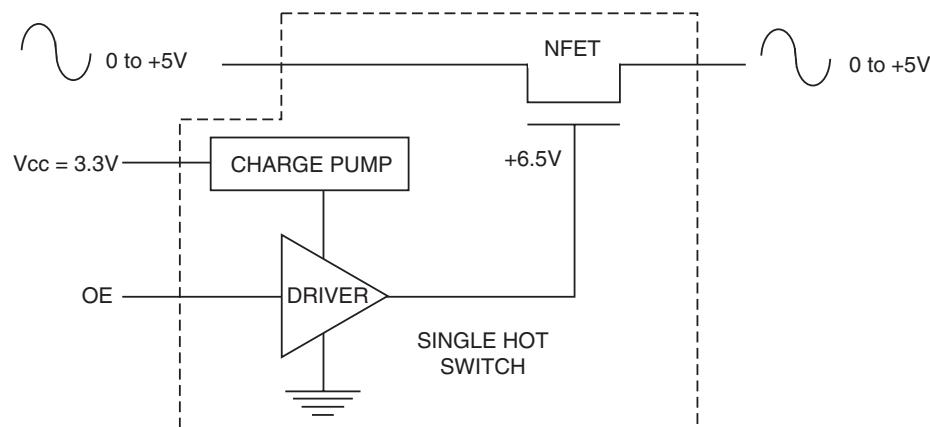
TA = -40°C to +85°C

Symbol	Parameter	V <sub>CC</sub> = 2.5 ± 0.2V <sup>(1)</sup>		V <sub>CC</sub> = 3.3 ± 0.3V <sup>(1)</sup>		Unit
		Min. <sup>(4)</sup>	Max.	Min. <sup>(4)</sup>	Max.	
t <sub>PLH</sub>	Data Propagation Delay <sup>(2,3)</sup> xAx to xBx or xBx to xAx	—	0.2	—	0.2	ns
t <sub>PHL</sub>	Switch Turn-On Delay Sx to xAx, xBx	1.5	11.5	1.5	11	ns
t <sub>PZH</sub>	Switch Turn-Off Delay Sx to xAx, xBx	1.5	11	1.5	10.5	ns
t <sub>PSX</sub>	Propagation Delay Sx to xAx, xBx	1.5	11	1.5	9	ns
f <sub>SX</sub>	Operating Frequency - Enable <sup>(2,5)</sup>	—	10	—	20	MHz

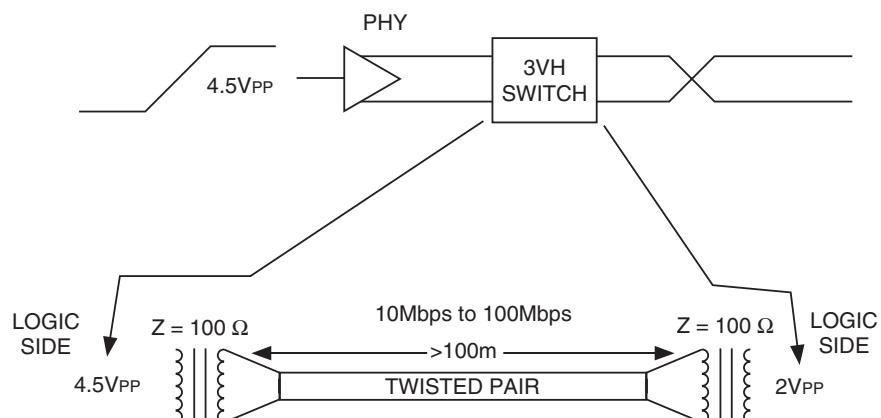
**NOTES:**

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at C<sub>L</sub> = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
4. Minimums are guaranteed but not production tested.
5. Maximum toggle frequency for Sx control input (pass voltage > V<sub>CC</sub>, V<sub>IN</sub> = 5V, R<sub>LOAD</sub> ≥ 1MΩ, no C<sub>LOAD</sub>).

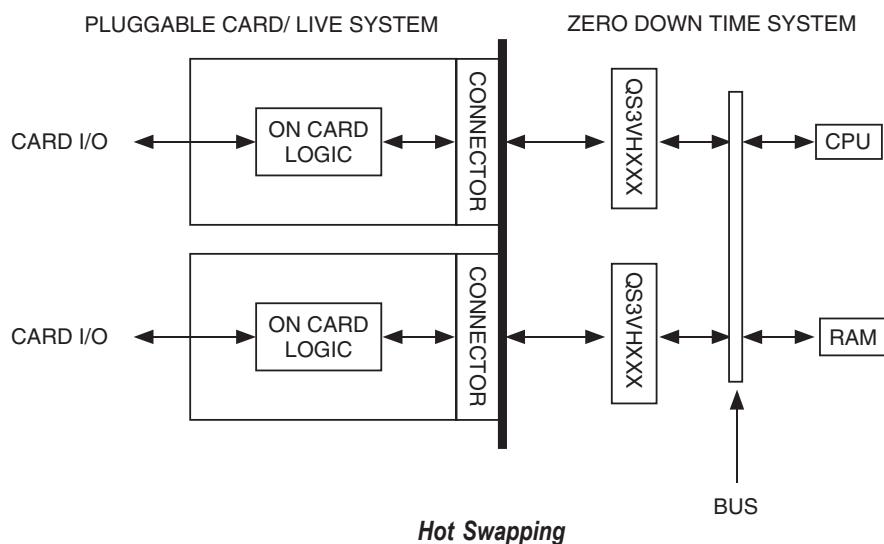
## SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



*Rail-to-Rail Switching*



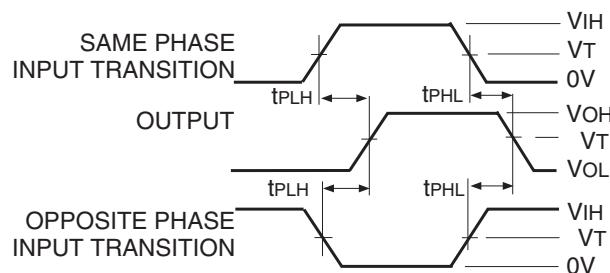
*Fast Ethernet Data Switching (LAN Switch)*



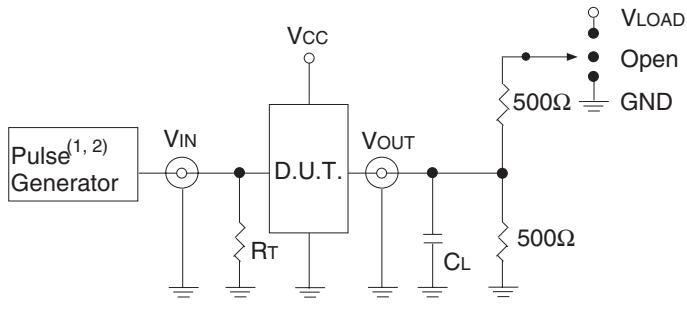
## TEST CIRCUITS AND WAVEFORMS

### TEST CONDITIONS

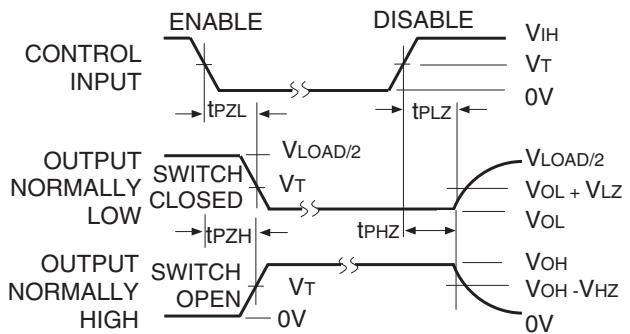
Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
$V_{LOAD}$	6	$2 \times V_{CC}$	V
$V_{IH}$	3	$V_{CC}$	V
$V_T$	1.5	$V_{CC}/2$	V
$V_{LZ}$	300	150	mV
$V_{HZ}$	300	150	mV
$C_L$	50	30	pF



Propagation Delay



Test Circuits for All Outputs



#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

#### Enable and Disable Times

#### DEFINITIONS:

$CL$  = Load capacitance: includes jig and probe capacitance.

$R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator.

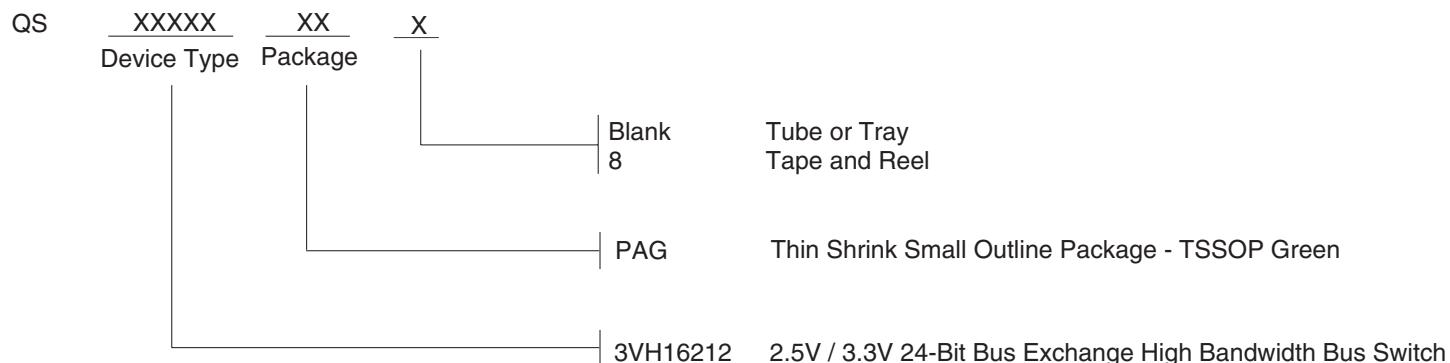
#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $t_f \leq 2.5\text{ns}$ ;  $t_r \leq 2.5\text{ns}$ .
2. Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $t_f \leq 2\text{ns}$ ;  $t_r \leq 2\text{ns}$ .

### SWITCH POSITION

Test	Switch
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND
$t_{PD}$	Open

## ORDERING INFORMATION



## Datasheet Document History

01/31/13

Pg. 1, 8

Updated the Ordering Information by removing non green package version, and Adding Tape and Reel information.

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